

Supporting Information for

Ethanol-Processable, Highly Crystalline Conjugated Polymers for Eco-Friendly Fabrication of Organic Transistors and Solar Cells

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Table of Contents

Methods

Supplementary Figure S1-7

- Molar absorption coefficients of PPDT2FBT-A in ethanol and PPDT2FBT in chloroform
- Cyclic voltammograms of PPDT2FBT, PPDT2FBT-A, and Bis-C₆₀-A
- Output curves of PPDT2FBT-A OFET devices fabricated using (a) ethanol or (b) CB as the processing solvent, respectively.
- *J-V* characteristics of hole-only devices based on PPDT2FBT-A pristine films
- Photoluminescence of PPDT2FBT-A pristine polymer and PPDT2FBT-A:Bis-C₆₀-A blend film
- 2D-GIXS pattern and line profiles of PPDT2FBT-A:Bis-C₆₀-A blend film
- *J-V* characteristics of hole- and electron-only devices based on PPDT2FBT-A and Bis-C₆₀-A pristine films, and PPDT2FBT-A:Bis-C₆₀-A blend film

Supplementary Table S1-4

- List of *median lethal dose* (*LD*₅₀) for various solvents
- Chemical list in the Toxic Release Inventory
- Summary of photovoltaic properties of the ethanol-processed devices with different PPDT2FBT-A:Bis-C₆₀-A blend ratios
- Hole and electron mobilities of pristine and blend films measured by SCLC method

References

Reaction scheme for the synthesis of PPDT2FBT-A and Bis-C₆₀-A:

Step (a): Reaction of 4,6-dibromo-2,5-dihydroxybenzoic acid (**1**) with a poly(ether ether ketone) chain (**2**) to form intermediate **M1**.

Step (b): Reaction of intermediate **M1** with a tin-substituted benzothiadiazole derivative (**M2**) to form the polymer **PPDT2FBT-A**.

Step (c): Reaction of Fullerene (C₆₀) with a poly(ether ether ketone) chain (**4**) to form **Bis-C₆₀-A**.

Structures of **R₁** and **R₂** are shown as poly(ether ether ketone) chains.

Synthesis: Fullerene (**C₆₀**) and 1,4-dibromo-2,5-dihydroxybenzene (**1**) were purchased from Solamer and Sigma-Aldrich and used without further purification. 1,3-Bis(2-(2-(2-methoxyethoxy)ethoxy)ethoxy)propan-2-yl-toluenesulfonate (**2**) and 3,4,5-(2-(2-(2-methoxyethoxy)ethoxy)ethoxy)benzaldehyde (**4**) were prepared as previously described.¹⁻² 1,4-Dibromo-2,5-bis(1,3-bis(2-(2-(2-methoxyethoxy)ethoxy)ethoxy)propan-2-yloxy)benzene (**M1**) was synthesized by following procedures. 1,4-Dibromo-2,5-dihydroxybenzene (**1**) (1.0 g, 3.8 mmol) was dissolved in ethanol (20 mL) and sodium *tert*-butoxide (0.77 g, 7.9 mmol)

was added. The mixture was stirred at room temperature for 1 h under a N₂ atmosphere. Compound **2** (4.2 g, 7.9 mmol) was added dropwise and the reaction mixture was stirred for 48 h under reflux. After partial evaporation of the solvent, H₂O was added and the mixture was extracted with dichloromethane (CH₂Cl₂). The organic extracts were washed with 10% sodium hydroxide (NaOH) solution, dried over anhydrous magnesium sulfate (MgSO₄) and the solvent was evaporated to afford the crude product. After silica gel column chromatography (SiO₂, eluent ethyl acetate/methanol = 95/5, v/v), a colorless oily compound, **M1** (0.7 g, 60%), was obtained. ¹H NMR (400 MHz, CDCl₃): δ (ppm) 7.30 (s, 2H), 4.33 (m, 2H), 3.69 (m, 8H), 3.56 (m, 30H), 3.48 (m, 8H), 3.30 (s, 12H); ¹³C NMR (100 MHz, CDCl₃): δ (ppm) 150.4, 121.8, 112.5, 80.6, 71.7, 70.5, 70.4, 70.3, 58.9.

OFET device fabrication and characterization: OEFTs were fabricated in a bottom-gate and top-contact configuration to characterize the electrical performance of PPDT2FBT-A using either CB or ethanol as the processing solvent. A highly *n*-doped (100) Si wafer (< 0.005 Ω cm) with a thermally grown 300 nm-thick SiO₂ layer (C_i = 10 nF cm⁻²) was utilized as the gate and dielectric. The SiO₂/Si wafers were treated with an OTS self-assembled monolayer as previously reported.³ The substrates were then washed sequentially with toluene, acetone, and isopropyl alcohol, and dried with nitrogen gas. PPDT2FBT-A was dissolved in ethanol or CB at ~2 mg mL⁻¹ and stirred at 80 °C for 5 h, filtered through a 0.2 μ m membrane, and spin-coated at 3000 rpm for 50 s onto the OTS-treated SiO₂/Si substrate. Au electrodes (40 nm thick) were thermally evaporated through a shadow mask onto the semiconducting active layer. The electrical performance of the FETs was measured in a N₂-filled glovebox using a Keithley 4200 semiconductor parametric analyzer. The field-effect mobility was estimated in the saturation regime ($|V_{DS}| > |V_{GS} - V_T|$) using the following

equation:

$$I_{DS} = \mu \frac{WC_i}{2L} (V_{GS} - V_T)^2$$

where I_{DS} is the drain-to-source current, W and L are the semiconductor channel width and length, respectively, μ is the mobility, C_i is the capacitance per unit area of the dielectric, and V_{GS} and V_T are the gate and threshold voltage, respectively.

SCLC Measurements: Hole- and electron-only devices with pristine PPDT2FBT-A, Bis-C₆₀-A, and their blend films as the active layer were measured by the SCLC method using ITO/PEDOT:PSS/active layer/Au (hole-only) and ITO/ZnO/active layers/Ca/Al (electron-only) device structures, respectively. The films were prepared as described in the device fabrication section. A range of 0-8 V was used for the current-voltage measurement, and the results were fitted to the Mott-Gurney equation:

$$J_{SCLC} = \frac{9}{8} \varepsilon \varepsilon_0 \mu \frac{V^2}{L^3}$$

where ε_0 is the permittivity of free space (8.85×10^{-14} F cm⁻¹), ε is the relative dielectric constant of the active layer, μ is the charge carrier mobility, V is the potential across the device ($V = V_{\text{applied}} - V_{\text{bi}} - V_{\text{series}}$) corrected for potential loss due to built-in potential (V_{bi}) and series resistance (V_{series}), and L is the active layer thickness.

Fabrication and characterization of inverted-type ethanol-processed PSCs: The inverted device with an ITO/ZnO/active layer/MoO₃/Ag architecture was used to evaluate the photovoltaic properties of ethanol-processed solar cells. ITO-coated glass substrates were subjected to ultra-sonication and cleaned with various solvents, i.e., acetone, deionized water,

and finally isopropyl alcohol. After the cleaning process, the substrates were kept in an 80 °C oven for 20 min. The ITO substrates were treated with UV-ozone (10 min) before spin-casting a ZnO layer. The ZnO solution was prepared by dissolving zinc acetate dihydrate ($\text{Zn}(\text{O}_2\text{CCH}_3)_2 \cdot (\text{H}_2\text{O})_2$, 99.9%, 1 g) and ethanolamine ($\text{HOCH}_2\text{CH}_2\text{NH}_2$, 99.5%, 0.28 g) in anhydrous 2-methoxy ethanol ($\text{CH}_3\text{OCH}_2\text{CH}_2\text{OH}$, >99.8%, 10 mL) under vigorous stirring for > 24 h to allow the hydrolysis reaction and aging to occur. The ZnO solution was spin-coated on top of the ITO substrates at 4000 rpm to produce a 40 nm thick ZnO layer. After the films were baked at 200 °C for 10 min in ambient condition, the devices were moved to a N_2 -filled glove box. Electron donor PPDT2FBT-A was blended with Bis- C_{60} -A electron acceptor in ethanol, where the D:A blend ratios were varied from 1:1 to 1:2 (w/w), and the concentration of the polymer donor in the blend solution was 5 mg mL⁻¹. The solutions were stirred for 1 h on a hot plate at 80 °C before spin-casting onto ITO/ZnO substrates at 1000 rpm for 40 s. The resulting thickness of the ethanol-processed blend film was measured to be 50–60 nm. The devices were baked for 20 min at 110 °C under vacuum for removal of residual ethanol in the active layer. The substrates were placed in an evaporation chamber under high vacuum ($< 10^{-6}$ Torr) for ~1 h before deposition of MoO_3 (10 nm) and Ag (120 nm). The active area of the fabricated device was 0.09 cm², as measured by optical microscopy. The current density-voltage (*J-V*) characteristics of the devices were measured under AM 1.5G solar irradiation (100 mWcm⁻², Peccell: PEC-L01) at ambient condition. This solar simulator system satisfied the Class AAB, ASTM Standards. The intensity of the solar simulator was calibrated using a standard silicon reference cell with a KG-5 visible color filter. The *J-V* characteristics were measured using a Keithley 2400 SMU. The EQE data were obtained using a spectral measurement system (K3100 IQX, Mc Science Inc.) with monochromatic light from a xenon arc lamp at 300 W filtered by a monochromator

(Newport) and an optical chopper (MC 2000 Thor labs). The EQE data were acquired in the dark. The calculated J_{SC} value was acquired by integrating the product of the EQE and the AM 1.5G solar spectrum, and showed good agreement with the measured J_{SC} , within 2% error.

Supplementary Figure S1-7

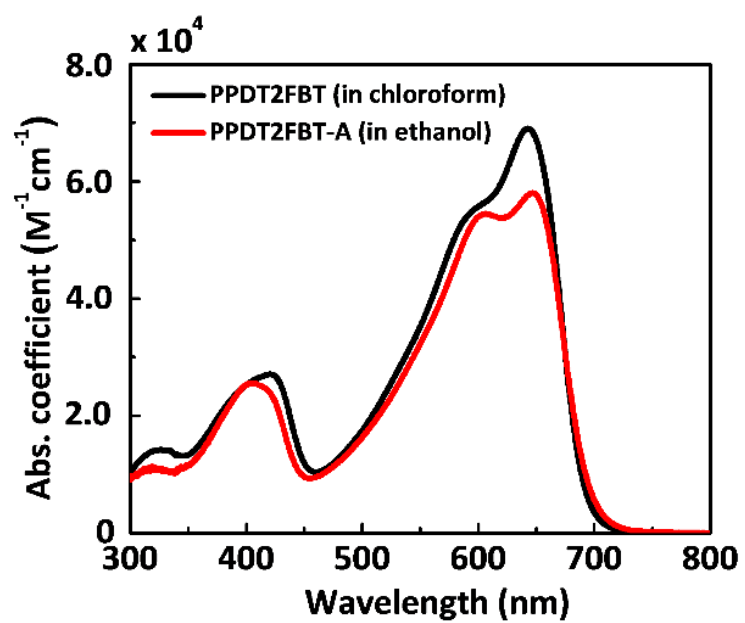


Figure S1. Molar absorption coefficients of PPDT2FBT-A in ethanol and PPDT2FBT in chloroform.

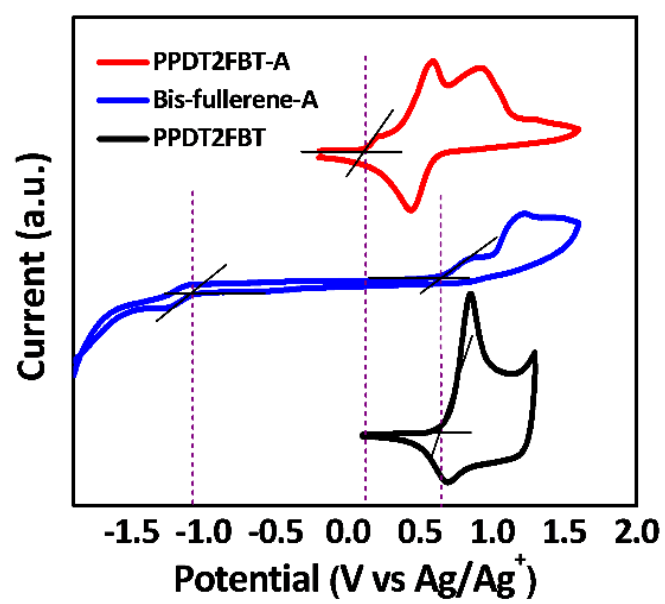


Figure S2. Cyclic voltammograms of PPDT2FBT, PPDT2FBT-A and Bis-C₆₀-A.

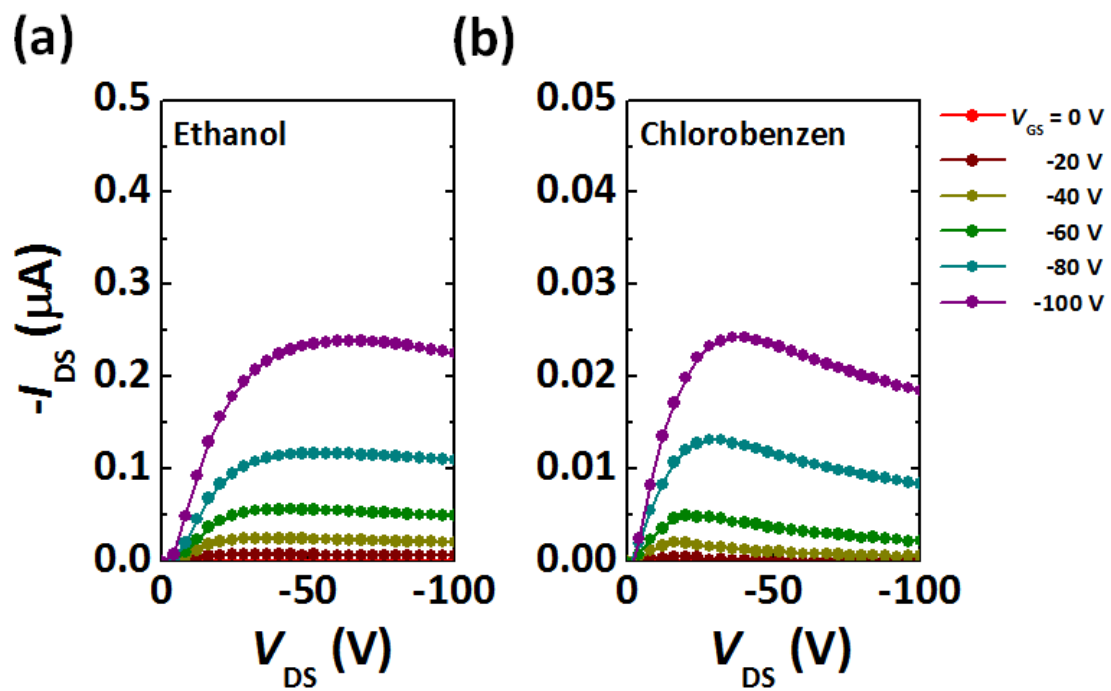


Figure S3. Output curves of PPDT2FBT-A OFET devices fabricated using (a) ethanol or (b) CB as the processing solvent, respectively.

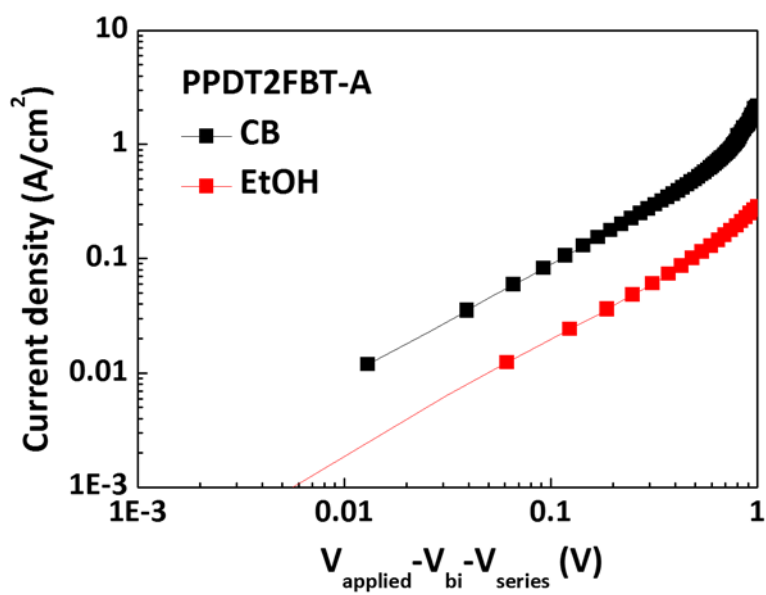


Figure S4. J - V characteristics of hole-only devices based on PPDT2FBT-A pristine films processed with CB (black line), EtOH (red line). Both devices were thermally annealed at 150°C for 30 min.

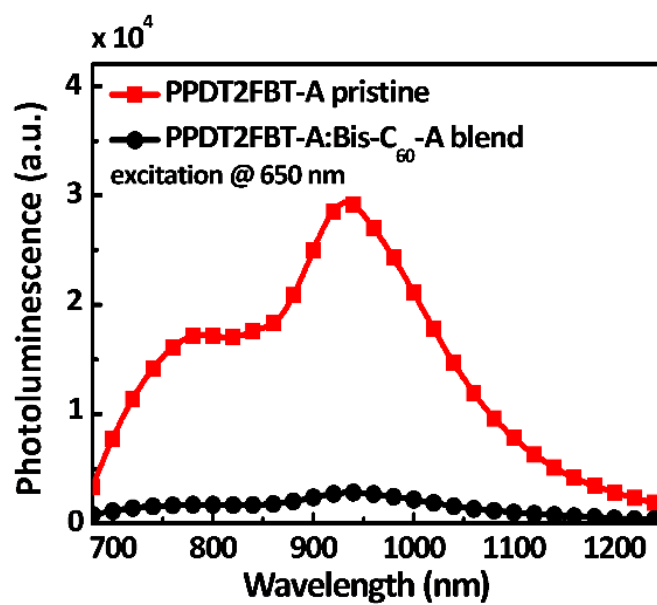


Figure S5. Photoluminescence of PPDT2FBT-A pristine polymer and PPDT2FBT-A:Bis-C₆₀-A blend films.

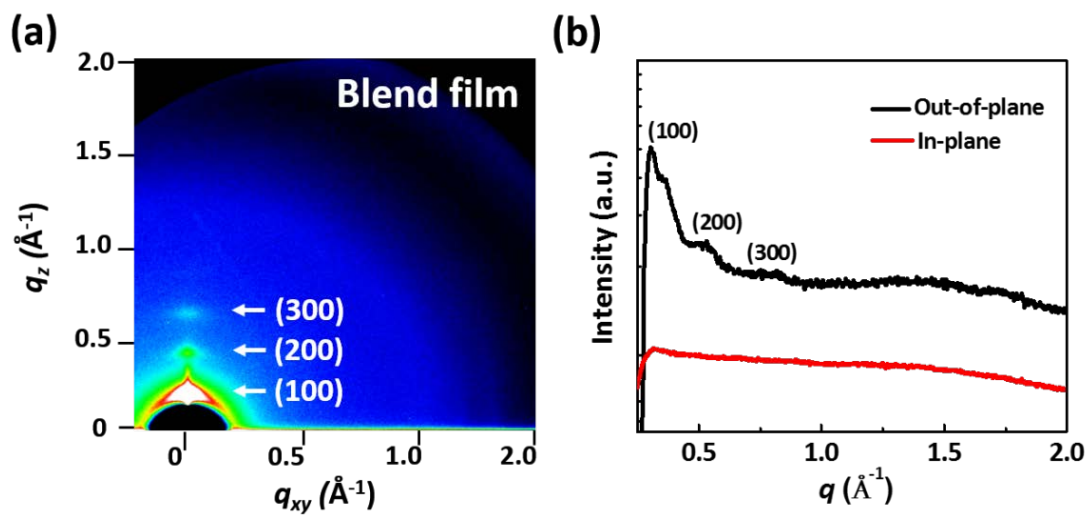


Figure S6. (a) 2D-GIXS pattern and (b) line profiles of PPDT2FBT-A:Bis-C₆₀-A blend film.

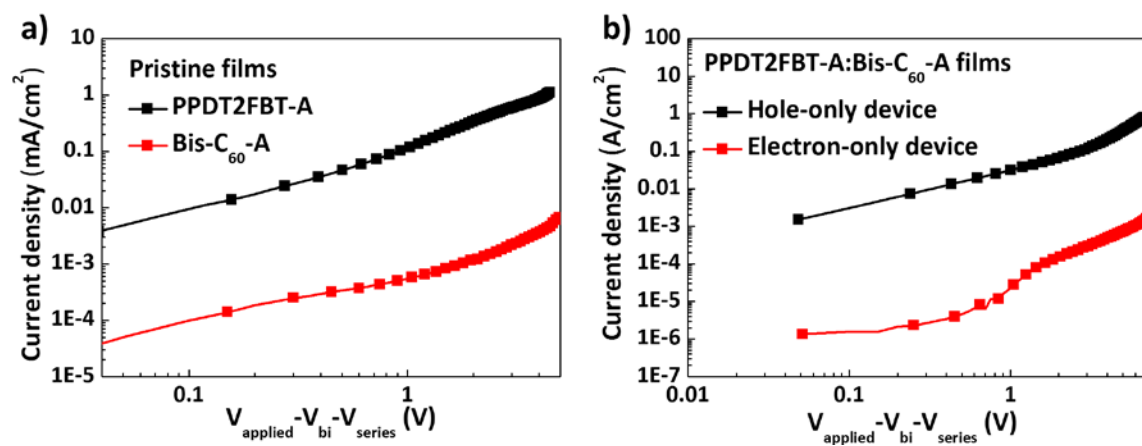


Figure S7. *J-V* characteristics of hole- and electron-only devices based on (a) PPDT2FBT-A and Bis-C₆₀-A pristine films, and (b) PPDT2FBT-A:Bis-C₆₀-A blend film.

Supplementary Table S1-4

Table S1. List of *median lethal dose (LD₅₀)* for various solvents.⁴

| Solvent | Animal, route | Median lethal dose (LD ₅₀) ^{a)} |
|-------------------------|------------------------|--|
| Ethanol | rat, oral | 10,470 mg/kg |
| Acetone | rat, oral | 5,800 mg/kg |
| Ethyl acetate | rat, oral | 5,620 mg/kg |
| Toluene | rat, oral | 5,580 mg/kg |
| Isopropyl alcohol | rat, oral | 5,045 mg/kg |
| 2-Methyltetrahydrofuran | rat, oral | 4,500 mg/kg |
| 1-Methyl-2-pyrrolidone | rat, oral | 3,914 mg/kg |
| Anisole | rat, oral | 3,700 mg/kg |
| Methanol | rat, oral | 2,769 mg/kg |
| o-Xylene | mouse, intraperitoneal | 1,364 mg/kg |
| 1-Chloronaphthalene | rat, oral | 1,540 mg/kg |
| Chlorobenzene | rat, oral | 1,110 mg/kg |
| Chloroform | rat, oral | 908 mg/kg |
| 1,2-Dichlorobenzene | rat, oral | 500 mg/kg |

^{a)}Median lethal dose (LD₅₀): the amount of the substance required (per body weight) to kill 50% of the test population.

Table S2. Chemical list in the Toxic Release Inventory.⁵

| Solvent | De minimus % Limit |
|--------------------------|--------------------|
| Ethanol | - |
| Toluene | 1.0 |
| Isopropyl alcohol | 1.0 |
| 1-Methyl-2-pyrrolidinone | 1.0 |
| Benzene | 0.1 |
| Methanol | 1.0 |
| o-Xylene | 1.0 |
| Chlorobenzene | 1.0 |
| Chloroform | 0.1 |
| 1,2-Dichlorobenzene | 1.0 |

Table S3. Summary of photovoltaic properties of the ethanol-processed devices with different PPDT2FBT-A:Bis-C₆₀-A blend ratios.

| D:A weight ratio | V_{OC} (V) | J_{sc} (mA cm ⁻²) | FF | PCE _{avg} (%) |
|---------------------|-----------------|------------------------------------|------------|---------------------------|
| 1:1 | 0.79±0.019 | 1.68±0.12 | 0.32±0.034 | 0.43±0.03 |
| 1:1.5 | 0.79±0.015 | 2.21±0.11 | 0.38±0.019 | 0.67±0.02 |
| 1:2 | 0.80±0.015 | 1.61±0.10 | 0.40±0.019 | 0.51±0.03 |

The average PCEs (\pm standard deviation) were derived from 10 different devices for each different system.

Table S4. Hole and electron mobilities of pristine and blend films measured by SCLC method

| | $\mu_{\text{h, SCLC}} (\text{max})$ ($\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$) | $\mu_{\text{h, SCLC}} (\text{avg})$ ($\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$) | $\mu_{\text{e, SCLC}} (\text{max})$ ($\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$) | $\mu_{\text{e, SCLC}} (\text{avg})$ ($\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$) |
|-----------------------------------|--|--|--|--|
| PPDT2FBT-A | 7.5×10^{-5} | 5.0×10^{-5} ($\pm 2.6 \times 10^{-5}$) ^{a)} | - | - |
| Bis-C ₆₀ -A | - | - | 8.8×10^{-7} | 5.3×10^{-7} ($\pm 2.7 \times 10^{-7}$) ^{a)} |
| PPDT2FBT-A:Bis-C ₆₀ -A | 2.6×10^{-5} | 2.1×10^{-5} ($\pm 4.6 \times 10^{-6}$) ^{a)} | 2.3×10^{-8} | 1.7×10^{-8} ($\pm 7.8 \times 10^{-9}$) ^{a)} |

The maximum and average mobilities obtained from at least 5 SCLC devices. ^{a)} Standard deviation.

III. References

- (1) Vandenbergh, J.; Dergent, J.; Conings, B.; Gopala Krishna, T. V. V.; Maes, W.; Cleij, T. J.; Lutsen, L.; Manca, J.; Vanderzande, D. J. M., Synthesis and characterization of water-soluble poly(p-phenylene vinylene) derivatives via the dithiocarbamate precursor route. *Eur. Polym. J.* **2011**, *47*, 1827-1835.
- (2) Xie, Y.; Akada, M.; Hill, J. P.; Ji, Q.; Charvet, R.; Ariga, K., Real time self-assembly and reassembly of molecular nanowires of trigeminal amphiphile porphyrins. *Chem. Commun.* **2011**, *47*, 2285-2287.
- (3) Ito, Y.; Virkar, A. A.; Mannsfeld, S.; Oh, J. H.; Toney, M.; Locklin, J.; Bao, Z. Crystalline ultrasmooth self-assembled monolayers of alkylsilanes for organic field-effect transistors. *J. Am. Chem. Soc.* **2009**, *131*, 9396-9404.
- (4) Materials Safety Data Sheet. <http://www.sigmaaldrich.com>.
- (5) U.S. Environmental Protection Agency. <https://www.epa.gov/toxics-release-inventory-tri-program/tri-listed-chemicals>.